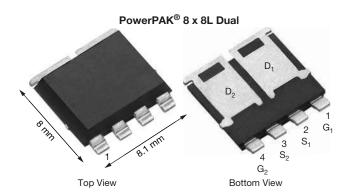


Vishay Siliconix

Automotive Dual N-Channel 80 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY					
V _{DS} (V)	80				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.0135				
$R_{DS(on)}$ (Ω) at $V_{GS} = 4.5 \text{ V}$	0.0170				
I _D (A) per leg	36				
Configuration	Dual				
Package	PowerPAK 8 x 8L				

FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Fully lead (Pb)-free device

N-Channel MOSFET

 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>





COMPLIANT HALOGEN FREE

D ₁ O	D ₂
G ₁	G_2
O S ₁	0 S ₂

N-Channel MOSFET

ABSOLUTE MAXIMUM RATING	S (T _C = 25 °C, unless	otherwise noted	1)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	80	V	
Gate-source voltage		V _{GS}	± 20	V	
Continuous drain current	T _C = 25 °C a	1	36		
Continuous drain current	T _C = 125 °C	I _D	21		
Continuous source current (diode conductio	n) ^a	I _S	34	Α	
Pulsed drain current ^b	I _{DM}	128			
Single pulse avalanche current	L = 0.1 mH	I _{AS}	27		
ingle pulse avalanche energy		E _{AS}	36	mJ	
Maximum power dissipation ^b	T _C = 25 °C	В	187	W	
Maximum power dissipation ~	T _C = 125 °C	P_{D}	62	VV	
Operating junction and storage temperature	T _J , T _{stg}	-55 to +175	°C		
Soldering recommendations (peak temperat		260	C		

THERMAL RESISTANCE RATINGS							
PARAMETER		SYMBOL	LIMIT	UNIT			
Junction-to-ambient	PCB mount c		100	°C/W			
Junction-to-case (drain)		R_{thJC}	4.0	C/VV			

Notes

- a. Package limited
- b. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- c. When mounted on 1" square PCB (FR4 material)
- d. See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK 8 x 8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V _{DS}	V _{GS}	= 0, I _D = 250 μA	80	-	-	V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	· V _{GS} , I _D = 250 μA	1.5	2	2.5	\ \
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 20 V	-	-	1	
Zero gate voltage drain current	I _{DSS}	V _{GS} = 0 V	V _{DS} = 80 V, T _J = 125 °C	-	-	50	μΑ
		V _{GS} = 0 V	V _{DS} = 80 V, T _J = 175 °C	-	-	150	1
On-state drain current a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	40	-	-	Α
		V _{GS} = 10 V	I _D = 5 A	-	0.0036	0.0135	Ω
Drain actives on state registeres 3	Б	V _{GS} = 4.5 V	I _D = 5 A	-	0.0045	0.0170	
Drain-source on-state resistance a	R _{DS(on)}	V _{GS} = 10 V	I _D = 5 A, T _J = 125 °C	-	-	0.0220	
		V _{GS} = 10 V	I _D = 5 A, T _J = 175 °C	-	-	0.0280	
Forward Transconductance b	9fs	V _{DS}	= 15 V, I _D = 10 A	-	55	-	S
Dynamic ^b							
Input capacitance	C _{iss}			-	1595	1995	
Output capacitance	Coss	$V_{GS} = 0 V$	$V_{DS} = 40 \text{ V}, f = 1 \text{ MHz}$	-	616	770	pF
Reverse transfer capacitance	C _{rss}			-	23	30	
Total gate charge ^c	Qg			-	26	36	
Gate-source charge ^c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 40 \text{ V}, I_D = 10 \text{ A}$	-	5	-	nC
Gate-drain charge ^c	Q _{gd}			-	4		
Gate resistance	R _g	f = 1 MHz		0.7	1.1	1.9	Ω
Turn-on delay time ^c	t _{d(on)}			-	10	14	
Rise time ^c	t _r	$V_{DD} = 40 \text{ V}, \text{ R}_L = 4 \Omega$ $I_D \cong 10 \text{ A}, \text{ V}_{GEN} = 10 \text{ V}, \text{ R}_g = 1 \Omega$		-	3	5	ns
Turn-off delay time ^c	t _{d(off)}			-	21	27	
Fall time ^c	t _f			-	3	5	
Source-Drain Diode Ratings and Char	acteristics b						
Pulsed current a	I _{SM}			-	-	128	Α
		I _F = 40 A, V _{GS} = 0					

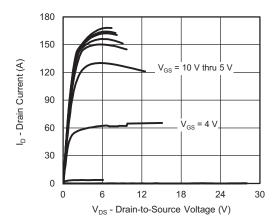
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

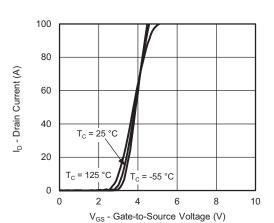
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



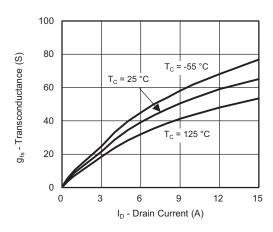
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



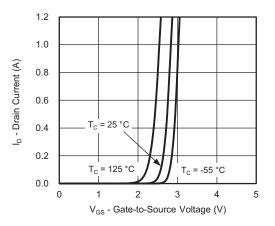
Output Characteristics



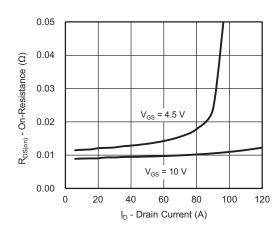
Transfer Characteristics



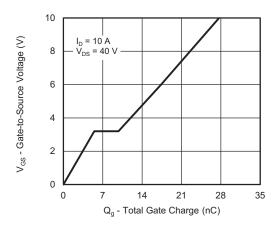
Transconductance



Transfer Characteristics



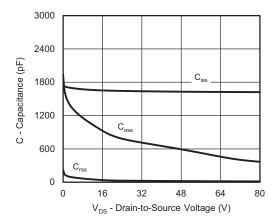
On-Resistance vs. Drain Current



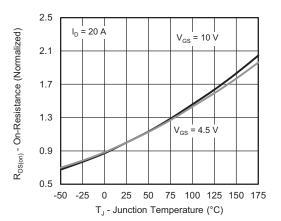
Capacitance



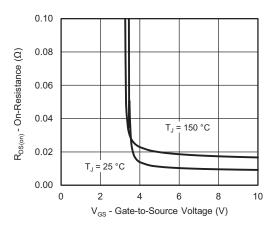
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



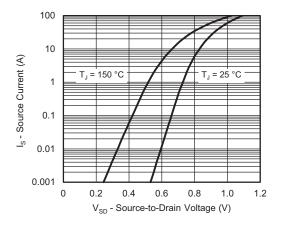
Capacitance



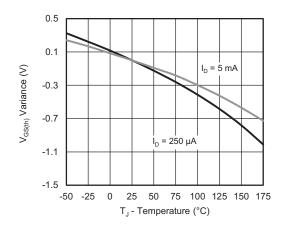
On-Resistance vs. Junction Temperature



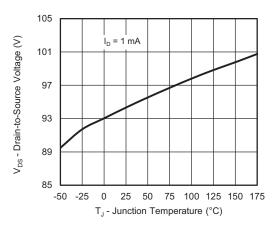
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage



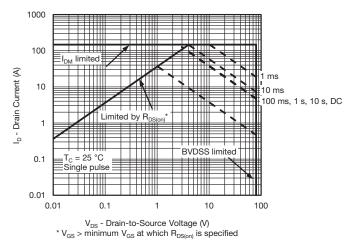
Threshold Voltage



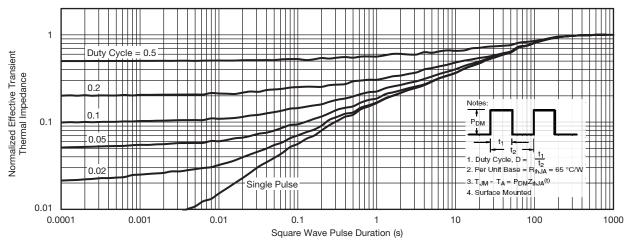
Drain Source Breakdown vs. Junction Temperature



THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



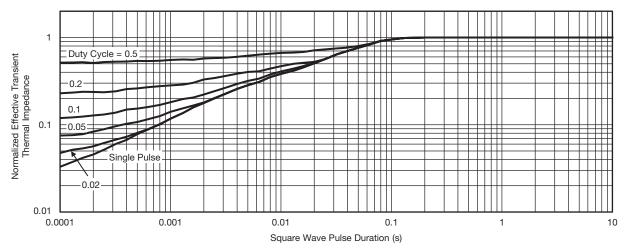
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

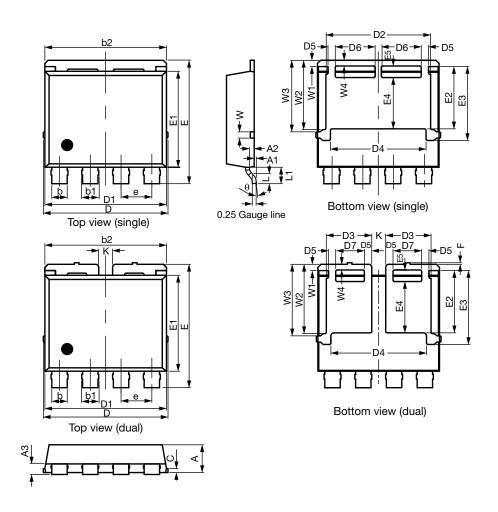
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction to Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction to Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg276465.



PowerPAK® 8 x 8L Case Outline



DIM		MILLIMETERS				
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
Α	1.70	1.80	1.90	0.067	0.071	0.075
A1	0.00	0.08	0.13	0.000	0.003	0.005
A2	0.25	0.30	0.35	0.010	0.012	0.014
A3	0.55	0.62	0.70	0.022	0.024	0.028
b	0.92	1.00	1.08	0.036	0.039	0.043
b1	1.02	1.10	1.18	0.040	0.043	0.046
b2	7.80	7.90	8.00	0.307	0.311	0.315
С	0.20	0.25	0.30	0.008	0.010	0.012
D	8.00	8.10	8.25	0.315	0.319	0.325
D1	7.80	7.90	8.00	0.307	0.311	0.315
D2	6.70	6.80	6.90	0.264	0.268	0.272
D3	2.85	2.95	3.05	0.112	0.116	0.120
D4	6.11	6.21	6.31	0.241	0.244	0.248
D5	0.37	0.47	0.57	0.015	0.019	0.022
D6	2.49	2.59	2.69	0.098	0.102	0.106
D7	1.76	1.86	1.96	0.069	0.073	0.077

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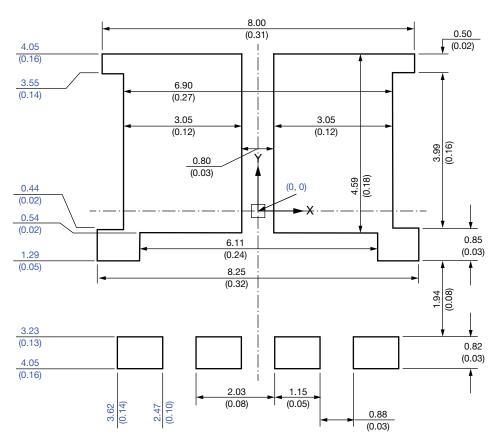
DIM		MILLIMETERS			INCHES			
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
е	1.95	2.00	2.05	0.077	0.079	0.081		
Е	7.90	8.00	8.10	0.311	0.315	0.319		
E1	6.12	6.22	6.32	0.241	0.245	0.249		
E2	3.94	4.04	4.14	0.140	0.159	0.163		
E3	4.69	4.79	4.89	0.185	0.189	0.193		
E4	3.23	3.33	3.43	0.127	0.131	0.135		
E5	0.65	0.75	0.85	0.026	0.030	0.033		
F	0.00	0.10	0.15	0.000	0.004	0.006		
L	0.62	0.72	0.82	0.024	0.028	0.032		
L1	0.92	1.07	1.22	0.036	0.042	0.048		
K	0.80	0.90	1.00	0.031	0.035	0.039		
W	0.30	0.40	0.50	0.012	0.016	0.020		
W1	0.30	0.40	0.50	0.012	0.016	0.020		
W2	4.39	4.49	4.59	0.173	0.177	0.181		
W3	4.54	4.64	4.74	0.179	0.183	0.187		
W4	0.32	0.37	0.42	0.013	0.015	0.017		
θ	6°	10°	14°	6°	10°	14°		

C17-1388-Rev. B, 16-Oct-17

DWG: 6026



Recommended Minimum PADs for PowerPAK® 8 x 8L Dual



Dimensions in millimeters (inches)

Note

• Linear dimensions are in black, the same information is provided in ordinate dimensions which are in blue.



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